

- **FEATURES**
- Blue enhanced
- Photovoltaic type
- Photoconductive type
- High quantum efficiency

DESCRIPTION: Low cost blue enhanced planar diffused silicon solderable photodiode. The PDB-V617 cell is designed for low noise, photovoltaic applications. The PDB-C617 cell is designed for low capacitance, high speed, photoconductive operation. They are available bare, PVC or buss wire leads.

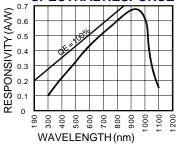


- Industrial controls
- Instrumentation

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	PDB-	C617	PDB-	V617	UNITS	
OTHEOL			MAX	MIN	MAX	oniro	
Vbr	Reverse Voltage		75		25	V	
T _{stg}	Storage Temperature	-40	+125	-40	+125	°C	
Το	Operating Temperature Range	-40	+100	-40	+100	°C	
Ts	Soldering Temperature		+224		+224	°C	
Ι	Light Current		500		500	mA	

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	PDB-C617			PDB-V617			
			MIN	TYP	MAX	MIN	TYP	MAX	UNITS
lsc	Short Circuit Current	H = 100 fc, 2850 K	725	800		650	720		mA
١D	Dark Current	H = 0, V _R = 5 V*		65	135		35	75	nA
Rsн	Shunt Resistance	H = 0, V _R = 10 mV	4.5	9		6.5	13.5		MΩ
TC RSH	RsH Temp. Coefficient	H = 0, V _R = 10 mV		-8			-8		%/°C
CJ	Junction Capacitance	H = 0, V _R = 5 V**		285			8500		pF
λrange	Spectral Application Range	Spot Scan	350		1100	350		1100	nm
λρ	Spectral Response - Peak	Spot Scan		940			940		nm
Vbr	Breakdown Voltage	I = 10 m A	25	50		5	15		V
NEP	Noise Equivalent Power	V _R = 0 V @ Peak	7.0 x 10 ⁻¹³ TYP		2.16 x 10 ⁻¹³ TYP			W/ \sqrt{Hz}	
tr	Response Time	$RL = 1 K\Omega V_R = 5 V^{**}$		40			2500		nS

*VR = 100 mV on Photovoltaic type **VR = 0 V on Photovoltaic type

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. [FORM NO. 100-PDB-C617-V617 REV N/C]